

Declaration of Electromagnetic Field Health Compliance for

AP6510DN-AGN-US

To whom it may concern,

As to the product <u>AP6510DN-AGN-US</u> made by Huawei Technologies Co., Ltd., we declare that it complies with the Basic restrictions/Reference levels for electric, magnetic and electromagnetic fields as specified in <u>47CFR §1.1310</u> based on the following calculation model assessment:

1. The power density according to far-field model is:

$$S = \frac{P \times G_{(\theta,\phi)}}{4 \times \pi \times R^2}$$

Where:

P =input power of the antenna.

G = antenna gain relative to an isotropic antenna.

 θ, ϕ = elevation and azimuth angles.

R = distance from the antenna to the point of investigation.

2. For single or multiple RF sources, the calculated power density should comply with following:

$$\sum_{i} \frac{S_i}{S_{Limit,i}} \leq 1$$

Where:

 S_i = the power density when the f is i.

 $S_{Limit,i}$ = the reference level requirement for power density when f is i.

- 3. The calculation of the power density or safe distance is:
 - NOTE 1: The RF exposure evaluation is base on the far-field and the radiation exposure is over-estimated.
 - NOTE 2: The maximum output power level is taken into account as a worst case for the purpose of the calculation of power density or safe distance.
 - NOTE 3: The minimum antenna feed cable loss (assumed no cable loss) is taken into account as a worst case for the purpose of the calculation of power density or safe distance.
 - NOTE 4: The maximum antenna radiation exposure orientation and maximum antenna gain is taken into account as a worst case for the purpose of the calculation of power density or safe distance.



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RF Source	Calculation		
RF Source #1	f	=	2400 to 2483.5 MHz
	$S_{Limit,i}$	=	10 W/m^2
	Р	=	0.241 W (= 23.82 dBm, measured max. for a peak value)
	G	=	2 (= 3 dBi)
	$ heta, \phi$	=	The worst condition is considered, i.e. the maximum G is used.
	R	>	0.2 m
	S _i	<	$\frac{P \times G_{(\theta,\phi)}}{4 \times \pi \times R^2} = 0.96 \text{W/m}^2$
	$\frac{S_i}{S_{Limit,i}}$	<	0.096
RF	— S		
Source(s)	$\sum \frac{S_i}{S_{i}}$	<	0.096 (Less than 1, so complied)
Combination	i [©] Limit,i		

Person responsible for making this declaration:

Signature

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Print Name

: Zhang Weimin

Position/Title : RF Engineer

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